SPICE Device Model Si3127DV



Vishay Siliconix

P-Channel 60 V (D-S) MOSFET

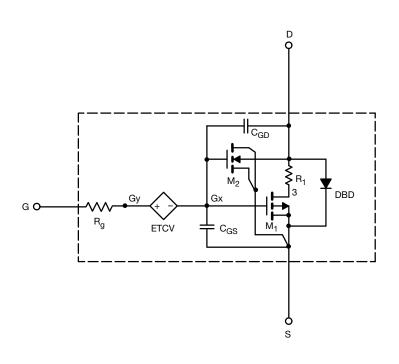
DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 °C to +125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage. A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Sub-circuit model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- Model the Gate Charge



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	2	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -3.5 \text{ A}$	0.071	0.074	Ω
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -3.1 \text{ A}$	0.098	0.095	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -30 \text{ V}, \text{ I}_{D} = -3.5 \text{ A}$	10	11	S
Diode Forward Voltage	V _{SD}	I _S = -2.8 A	-0.82	-0.85	V
Dynamic ^b	-				
Input Capacitance	Ciss	V_{DS} = -30 V, V_{GS} = 0 V, f = 1 MHz	831	832	pF
Output Capacitance	C _{oss}		88	88	
Reverse Transfer Capacitance	C _{rss}		62	63	
Total Gate Charge	Qg	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = -10 \text{ V}, \text{ I}_{D} = -3.5 \text{ A}$	16	20	nC
		$V_{DS} = -30$ V, $V_{GS} = -4.5$ V, $I_D = -3.5$ A	8.4	10.1	
Gate-Source Charge	Q _{gs}		3.3	3.3	
Gate-Drain Charge	Q _{gd}		3.9	3.9	

Notes

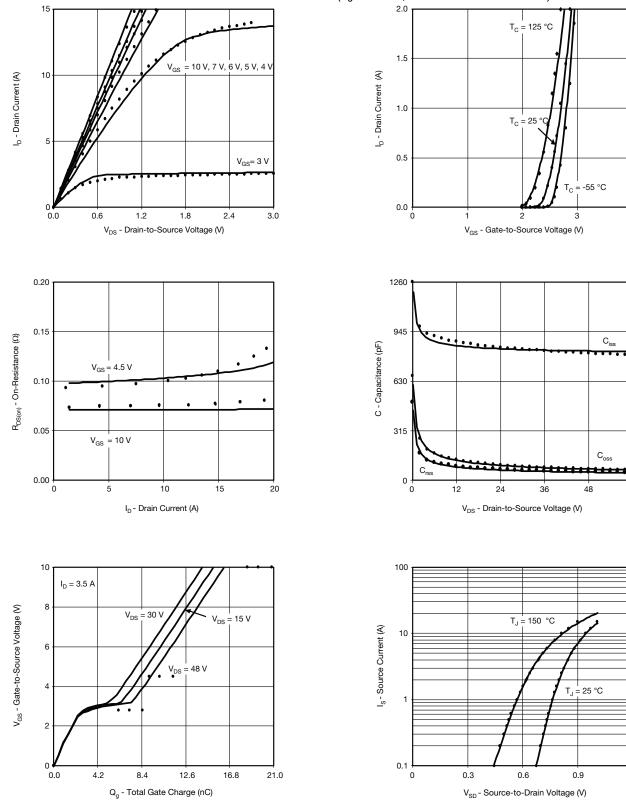
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.



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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)



Note

• Dots and squares represent measured data. Copyright: Vishay Intertechnology, Inc.

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